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BYX56 SERIES

CONTROLLED AVALANCHE RECTIFIER DIODES

Silicon diodes in a DO-5 metal envelope, capable of absorbing transients and intended for power rectifier applications.

The series consists of the following types:

Normal polarity (cathode to stud): BYX56-600 to BYX56-1400. Reverse polarity (anode to stud): BYX56-600R to BYX56-1400R.

QUICK REFERENCE DATA

		BYX56-600(R)		800(R) [1000(R)]		1200(R)	1400(R)	
Crest working reverse voltage	v_{RWM}	max.	600	800	1000	1200	1400	٧
Reverse avalanche breakdown voltage	V _{(BR)R}	>	750	1000	1250	1450	1650	٧
Average forward current	i _F (AV)	max.			48			Α
Non-repetitive peak forward current	^I FSM	max.			800			Α
Non-repetitive peak reverse power dissipation	PRSM	max.			40			kΙ

MECHANICAL DATA

MECHANICAL DA

Fig. 1 DO-5

15.3 max

3.8
min

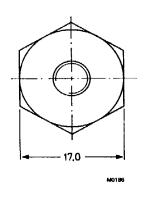
6.35
max

2.2
max

11.5
10.7

11.5
10.7

Dimensions in mm



Net mass: 22 g

Diameter of clearance hole: max. 6.5 mm

Accessories supplied on request: see ACCESSORIES section

Supplied with device: 1 nut, 1 lock washer.

Nut dimensions across the flats: 11.1 mm.

Torque on nut: min. 1.7 Nm (17 kg cm), max. 3.5 Nm (35 kg cm).

The mark shown applies to normal polarity types.

NJ Semi-Conductors reserves the right to change test conditions, parameter limits and package dimensions without notice. Information furnished by NJ Semi-Conductors is believed to be both accurate and reliable at the time of going to press. However, NJ Semi-Conductors assumes no responsibility for any errors or omissions discovered in its use. NJ Semi-Conductors encourages customers to verify that datasheets are current before placing orders.

Quality Semi-Conductors

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RATINGS

Limiting values in accordance with the Absolute Maximum System (IEC134)

Crest working reverse voltage V _{RWM} max. 600 800 Continuous reverse voltage V _R max. 600 800 Currents	1000	1200 1200	1400	v v
	1000	1200	1400	V
Currents	·			
Average forward current (averaged over any 20 ms period) up to T _{mb} = 112 °C at T _{mb} = 125 °C IF(A)			48 40	A A
R.M.S. forward current IF(RM	AS) max	ζ.	75	A
Repetitive peak forward current IFRM	max	ex. 450		Α
Non-repetitive peak forward current t = 10 ms (half sine-wave); T _j = 175 °C prior to surge; with reapplied VRWMmax	max	τ.	800	A
$l^2 t$ for fusing (t < 10 ms) $l^2 t$	i²t ma		200	A²s
Reverse power dissipation				
Repetitive peak reverse power dissipation $t = 10 \ \mu s$ (square-wave; $f = 50 \ Hz$); $T_j = 175 \ ^{\circ}C$ PRRM	kem j	۲.	6.5	kW
Non-repetitive peak reverse power dissipation $t = 10 \mu s$ (square-wave)				
$T_j = 25$ °C prior to surge	PRSM max. PRSM max.		40 6.5	kW kW
Temperatures				
Storage temperature T _{stg}		-55 to +	175	ос
Junction temperature T _j	max	i .	175	οС
THERMAL RESISTANCE				
From junction to mounting base Rth j-	mb =		8.0	oc/w
From mounting base to heatsink Rth m	b-h =		0.2	oc/w
Transient thermal impedance; $t = 1 \text{ ms}$ $Z_{th j-l}$	n =	C	0.03	oC/W

CHARACTERISTICS

		BYX56-600(R)		800(R)	1000(R)	1200(R)	1400(R)	
Forward voltage IF = 150 A; T _j = 25 °C	VF	<	1.8	1.8	1.8	1.8	1.8	 V*
Reverse avalanche breakdo voltage I _R = 5 mA; T _j = 25 °C	wn V _{(BR)R}	;, >	750	1000	1250	1450	1650	٧
Reverse current VR = VRWMmax; T _j = 125 °C	I _R	<	2400 1.6	1.6	2400 1.6	1.6	1.6	V mA

OPERATING NOTES

The top connector should neither be bent nor twisted; it should be soldered into the circuit so that there is no strain on it.

During soldering the heat conduction to the junction should be kept to a minimum by using a thermal shunt.

